

Code No: 114AE

R13**JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY HYDERABAD****B.Tech II Year II Semester Examinations, May - 2016****ELECTRONIC CIRCUITS****(Electrical and Electronics Engineering)****Time: 3 Hours****Max. Marks: 75****Note:** This question paper contains two parts A and B.

Part A is compulsory which carries 25 marks. Answer all questions in Part A.

Part B consists of 5 Units. Answer any one full question from each unit.

Each question carries 10 marks and may have a, b, c as sub questions.

PART-A**[25 Marks]**

- 1.a) Why is a CE amplifier widely used? List down its main limitations. [2]
- b) What are the main advantages of negative feedback? [3]
- c) What is base-spreading resistance? [2]
- d) What is the bypass capacitor and why it is connected in CE amplifier? [3]
- e) Name two different methods of pulse triggering. [2]
- f) What are the applications of voltage comparator? [3]
- g) What are the advantages of class-B operation? [2]
- h) What is high pass circuit? [3]
- i) Explain piece wise linear diode characteristics. [2]
- j) What are the transistor switching times? [3]

PART-B**[50 Marks]**

- 2.a) Derive the equations for: i) Voltage gain ii) Current gain iii) Input Resistance iv) Output resistance for BJT CE configuration using h-parameters model.
- b) A CE amplifier is drawn by a voltage source of internal resistance $R_s = 800 \text{ ohms}$ and load impedance is a resistance $R_L = 1000 \text{ ohms}$. The h-parameters are $h_{ie} = 1.0 \text{ K ohms}$, $h_{re} = 2 \times 10^{-4}$, $h_{fe} = 50$ and $h_{oe} = 25 \mu \text{ A/V}$. Compute A_i , R_i , A_v , R_o using approximate analysis. [5+5]

OR

- 3.a) Show that bandwidth increases in negative feedback amplifiers.
- b) An amplifier has an input resistance of 200 K ohms , with a certain negative feedback introduced in the above amplifier the input resistance is found to be 20 M ohms and overall gain is found to be 1000. Calculate the loop gain and feedback factor. [5+5]

- 4.a) Derive the equation for the lower 3dB frequency of CE configuration due to emitter bypass capacitor.
- b) Given the following transistor measurements made at $I_C = 5 \text{ mA}$ and $V_{CE} = 5 \text{ V}$ and at room temperature. $h_{ie} = 600 \text{ ohms}$, $h_{fe} = 100$, $C_{b'c} = 3 \text{ PF}$ and $A_i = 10$ at 10 MHz . Find f_β , f_T , $C_{b'e}$, $r_{b'e}$ and $r_{bb'}$ of hybrid equivalent circuit in CE configuration. [5+5]

OR

5. Derive all components in the Hybrid- π model in terms of h parameters in CE configuration. [10]

- 6.a) Design a collector coupled monostable multivibrator with the following specifications. $V_{cc} = +12V$, $V_{bb} = -6V$, $h_{FEmin} = 20$, $V_{EBO} = 5V$, $I_c = 20mA$. Transistors are of silicon npn type. Output pulse width = $200\mu sec$.

- b) With the help of a neat circuit diagram, explain the operation of a astable multivibrator. [5+5]

OR

- 7.a) With help of a neat circuit diagram and waveforms explain the operation of An Emitter coupled clipper.

- b) With help of a neat circuit diagram and waveforms explain the working of a negative clamping circuit. [5+5]

- 8.a) Derive the expression for maximum conversion efficiency for a simple series fed Class A power amplifier.

- b) List out the advantages of complementary symmetry configuration over push pull configuration. [5+5]

OR

- 9.a) Derive the expression for the percentage tilt of the output of high pass circuit with large time constant excited by a symmetrical square wave with zero average value.

- b) 1 kHz square wave output from an amplifier has rise time $t_r = 350ns$ and tilt is 5%. Determine the upper and lower 3-db frequencies. [5+5]

- 10 a) Explain the operation of transistor switch in saturation.

- b) For a common emitter amplifier, $V_{cc} = 15V$, $R_c = 1.5k\Omega$ and $I_B = 0.3 mA$.

- i) Determine the value of $h_{FE(min)}$ for saturation to occur.

- ii) If R_c is changed to 500Ω will the transistor be saturated. [5+5]

OR

- 11.a) Explain in detail about storage and transition times relating to diode switching times.

- b) Discuss in detail about transistor switching times. [5+5]

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